

**SEMITOP<sup>®</sup> 3**

## IGBT Module

**SK30GAD066T**

### Target Data

### Features

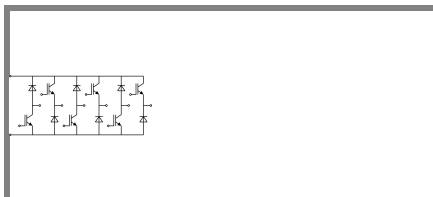
- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- Trench silicon structure
- High short circuit capability
- Low tail current with low temperature dependence
- Integrated PTC temperature sensor

### Typical Applications

- Switching (not for linear use)
- Inverter
- Switched mode power supplies
- UPS

### Remarks

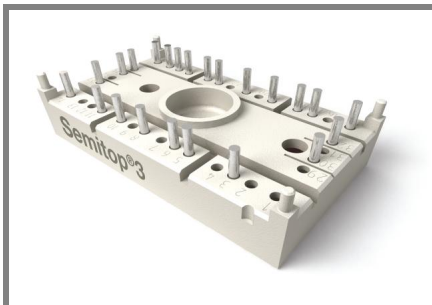
- PTC temp sensor test conditions:  
measuring current: 1 mA  
max measuring current value: 3 mA



**GAD**

Absolute Maximum Ratings		$T_s = 25\text{ °C}$ , unless otherwise specified	
Symbol	Conditions	Values	Units
<b>IGBT</b>			
$V_{CES}$	$T_j = 25\text{ °C}$	600	V
$I_C$	$T_j = 175\text{ °C}$	$T_s = 25\text{ °C}$	38 A
		$T_s = 70\text{ °C}$	31 A
$I_{CRM}$	$I_{CRM} = 2 \times I_{Cnom}$	60	A
$V_{GES}$		$\pm 20$	V
$t_{psc}$	$V_{CC} = 360\text{ V}; V_{GE} \leq 20\text{ V}; T_j = 125\text{ °C}$ $V_{CES} < 600\text{ V}$	6	$\mu\text{s}$
<b>Inverse Diode</b>			
$I_F$	$T_j = 150\text{ °C}$	$T_s = 25\text{ °C}$	A
		$T_s = 80\text{ °C}$	A
$I_{FRM}$	$I_{FRM} = 2 \times I_{Fnom}$		A
<b>Freewheeling Diode</b>			
$I_F$	$T_j = 175\text{ °C}$	$T_{case} = 25\text{ °C}$	65 A
		$T_{case} = 70\text{ °C}$	51 A
$I_{FRM}$	$I_{FRM} = 2 \times I_{Fnom}$	200	A
<b>Module</b>			
$I_{t(RMS)}$			A
$T_{vj}$		-40 ... +150	$^{\circ}\text{C}$
$T_{stg}$		-40 ... +125	$^{\circ}\text{C}$
$V_{isol}$	AC, 1 min.	2500	V

Characteristics		$T_s = 25\text{ °C}$ , unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
<b>IGBT</b>					
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 0,43\text{ mA}$	5	5,8	6,5	V
$I_{CES}$	$V_{GE} = 0\text{ V}, V_{CE} = V_{CES}$	$T_j = 25\text{ °C}$		0,08	mA
		$T_j = 125\text{ °C}$			mA
$I_{GES}$	$V_{CE} = 0\text{ V}, V_{GE} = 30\text{ V}$	$T_j = 25\text{ °C}$		300	nA
		$T_j = 125\text{ °C}$			nA
$V_{CE0}$		$T_j = 25\text{ °C}$	0,9	1	V
		$T_j = 150\text{ °C}$	0,85	0,9	V
$r_{CE}$	$V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}$	18	28	$\text{m}\Omega$
		$T_j = 150\text{ °C}$	27	38	$\text{m}\Omega$
$V_{CE(sat)}$	$I_{Cnom} = 30\text{ A}, V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}_{chiplev.}$	1,45	1,85	V
		$T_j = 150\text{ °C}_{chiplev.}$	1,65	2,05	V
$C_{ies}$	$V_{CE} = 25, V_{GE} = 0\text{ V}$	$f = 1\text{ MHz}$			nF
$C_{oes}$					nF
$C_{res}$					nF
$t_{d(on)}$	$R_{Gon} = 22\ \Omega$	$V_{CC} = 300\text{ V}$ $I_{Cnom} = 30\text{ A}$ $T_j = 150\text{ °C}$ $V_{GE} = \pm 15\text{ V}$	1,24		ns
$t_r$					ns
$E_{on}$					mJ
$t_{d(off)}$	$R_{Goff} = 22\ \Omega$				ns
$t_f$					ns
$E_{off}$				1,48	mJ
$R_{th(j-s)}$	per IGBT		1,8		K/W



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### Features

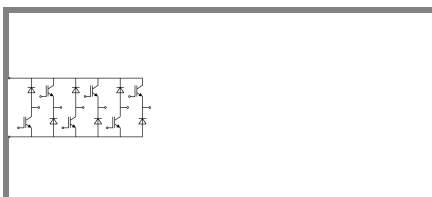
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max measuring current value: 3 mA

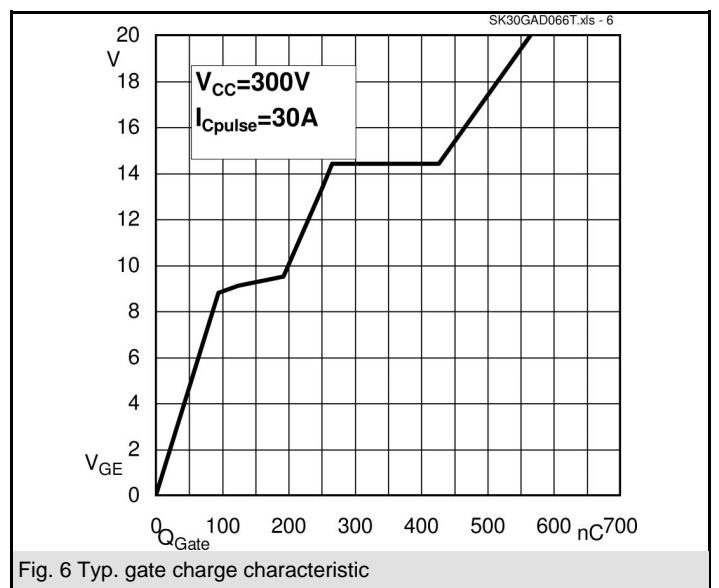
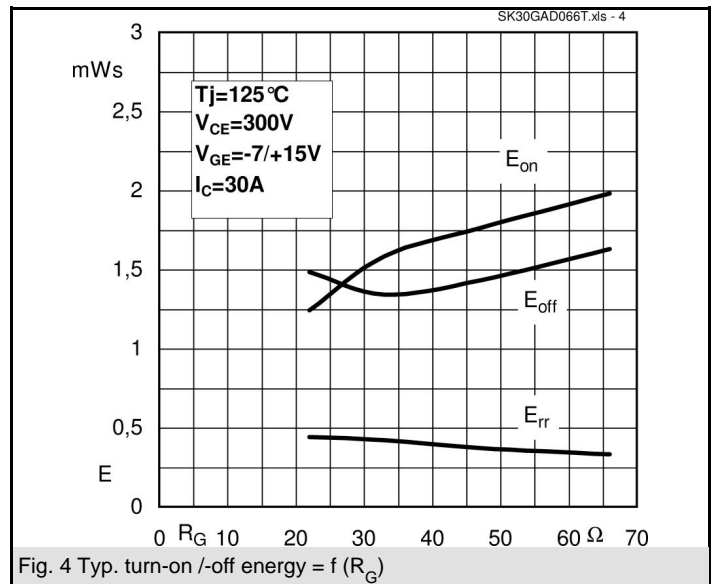
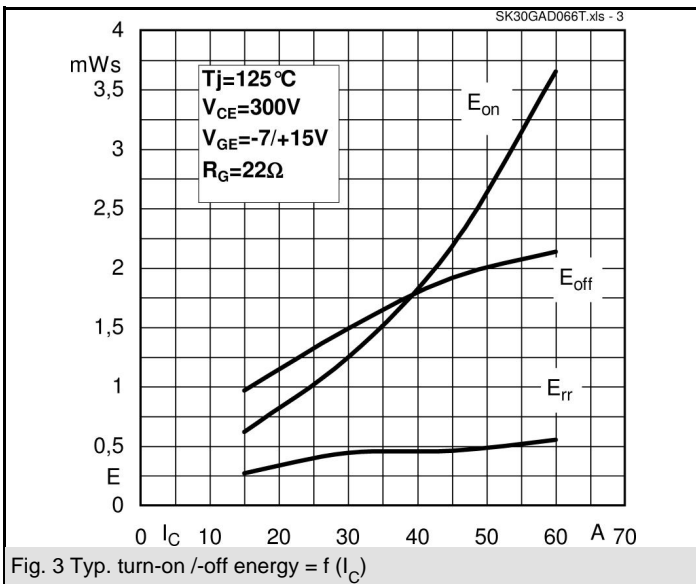
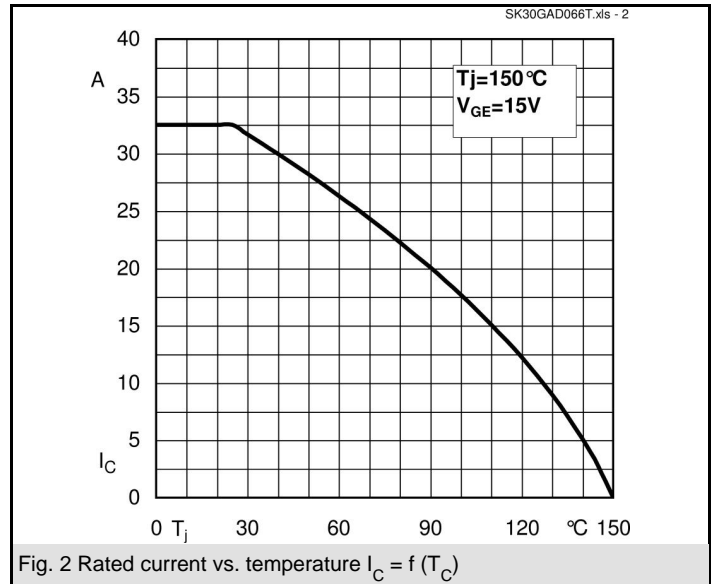
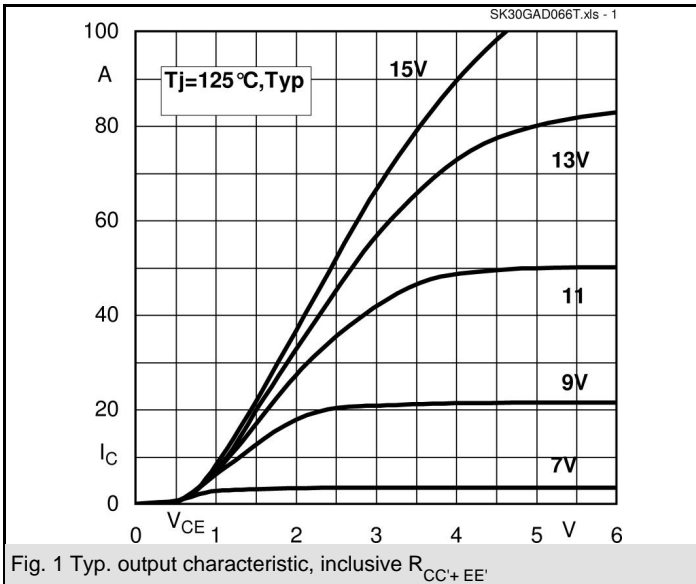


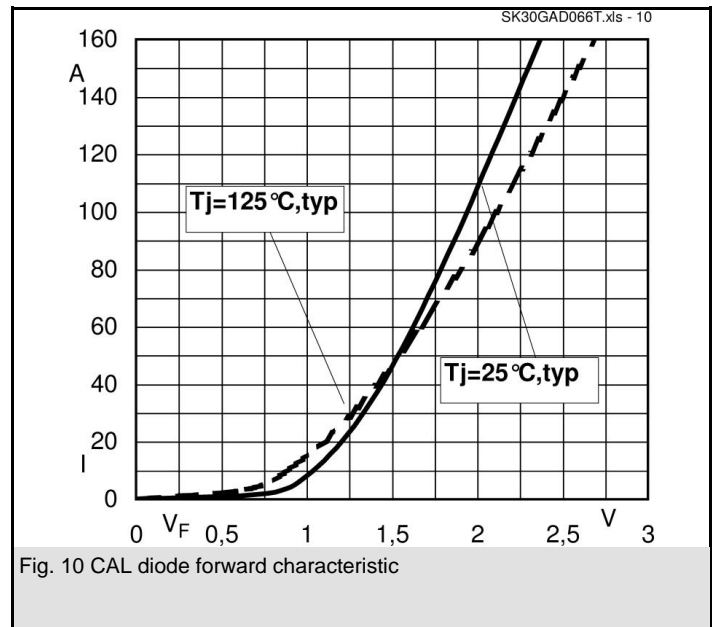
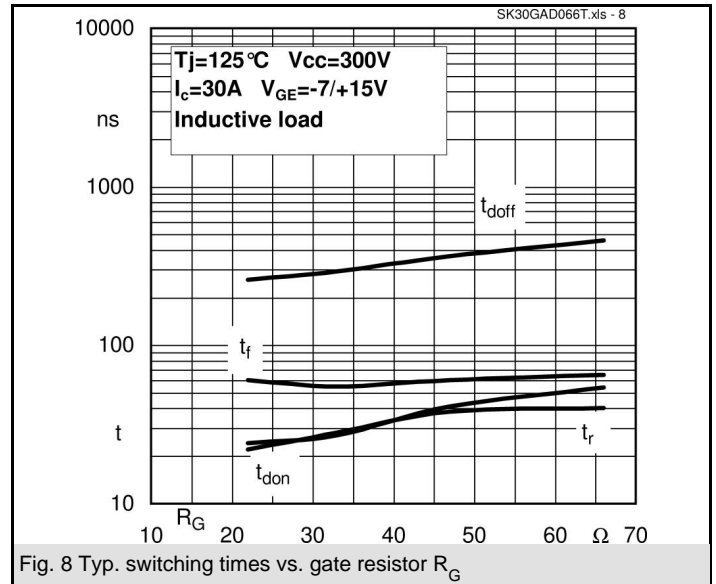
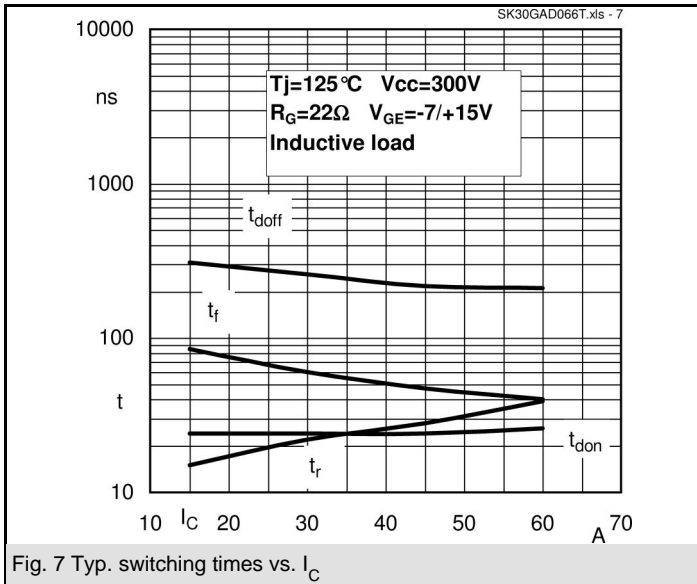
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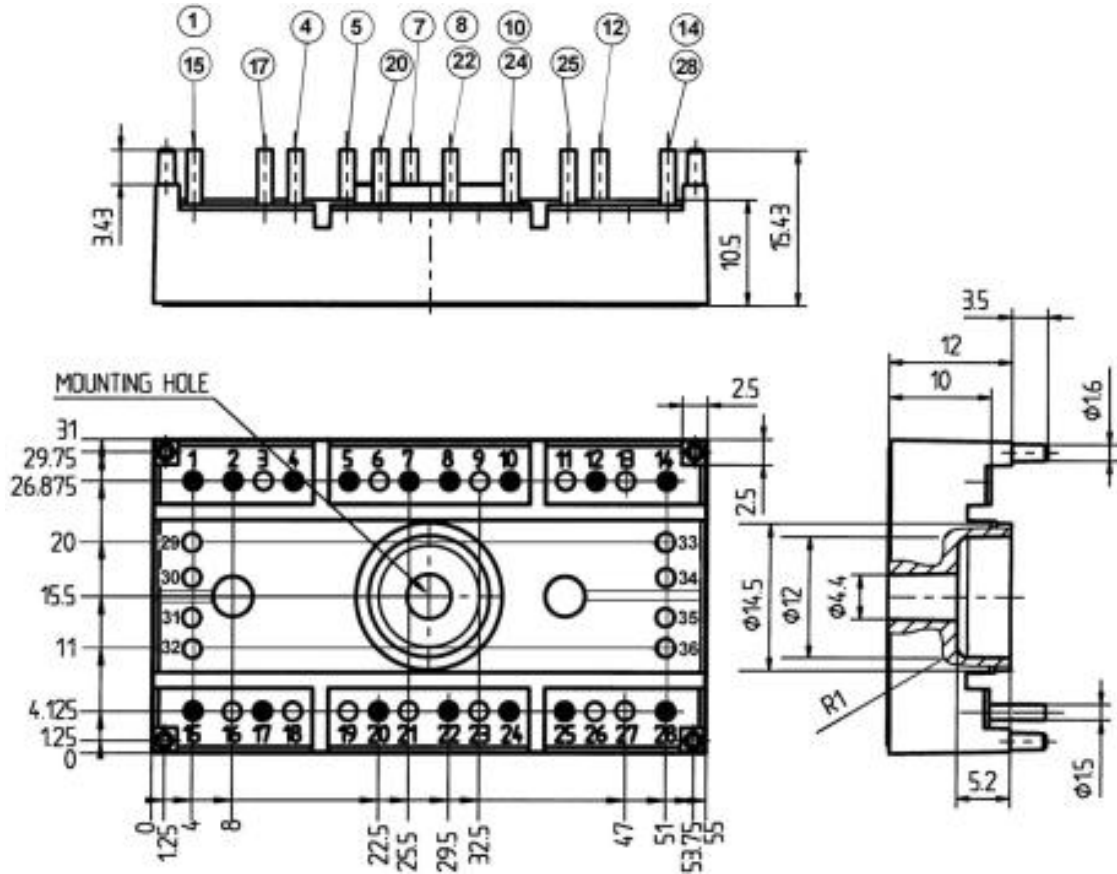
Characteristics		min.	typ.	max.	Units
<b>Symbol</b>	<b>Conditions</b>				
<b>Freewheeling Diode</b>					
$V_F = V_{EC}$	$I_{Fnom} = 30 \text{ A}; V_{GE} = 0 \text{ V}$		1,3	1,5	V
			1,2	1,45	V
$V_{F0}$			0,85	0,9	V
$r_F$			9	16	mΩ
$I_{RRM}$	$I_{Fnom} = 30 \text{ A}$		3		A
$Q_{rr}$	$di/dt = -500 \text{ A}/\mu\text{s}$		3		μC
$E_{rr}$	$V_{CC} = 300 \text{ V}$		0,44		mJ
$R_{th(j-s)FD}$	per diode			1,2	K/W
$M_s$	to heat sink M1	2,25		2,5	Nm
w			30		g
<b>Temperature sensor</b>					
$R_{ts}$	3%, $T_r = 25 (100)^\circ\text{C}$		1000 (1670)		Ω

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

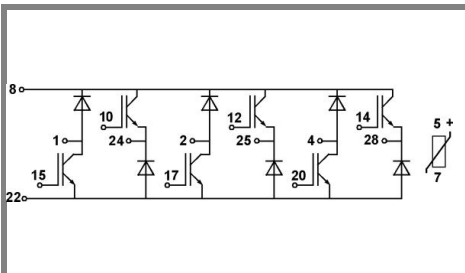
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Case T57 (Suggested hole diameter, in the PCB, for solder pins and plastic mounting pins: 2mm)



Case T 57

GAD